Inventor(s): Andrew J. WALKER et al. DOCKET NO.: 035905-0103

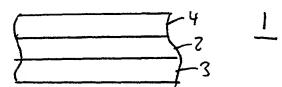


FIGURE 1

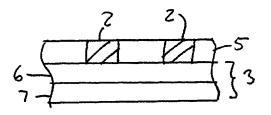


FIGURE 2A

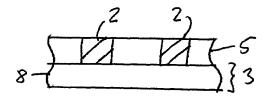


FIGURE 2B

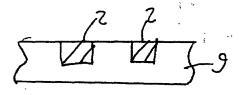


FIGURE 3

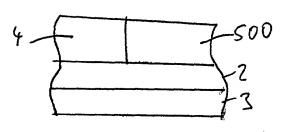


FIGURE 15

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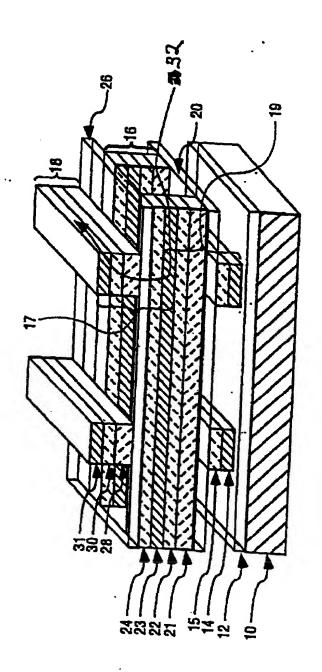
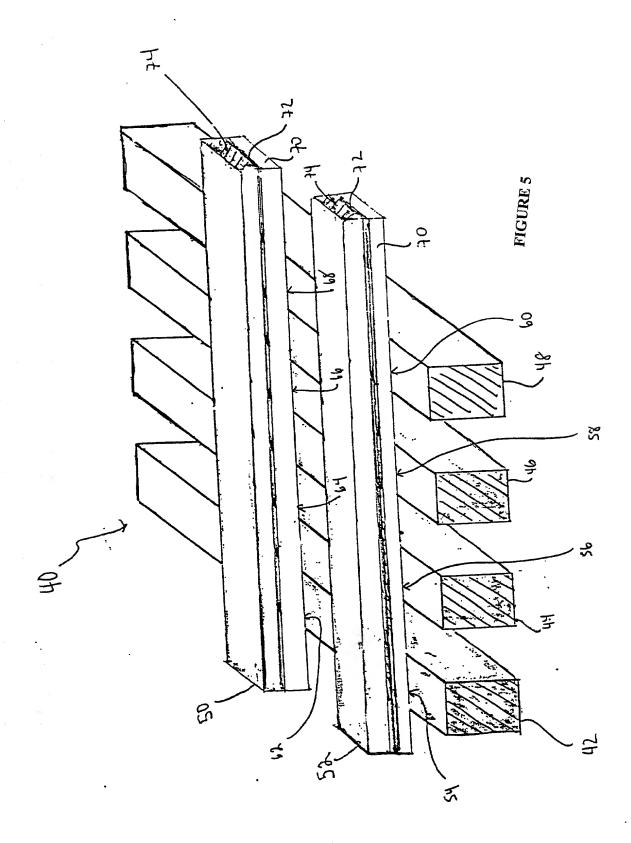


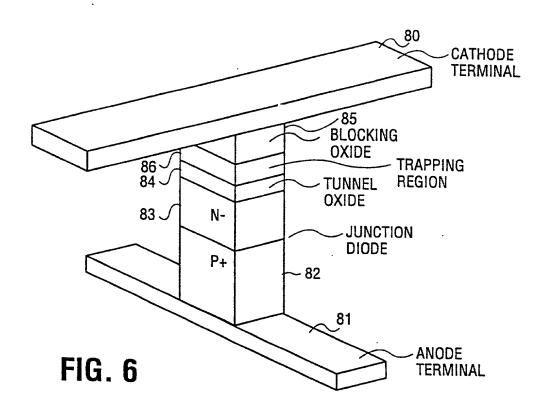
FIGURE 4A

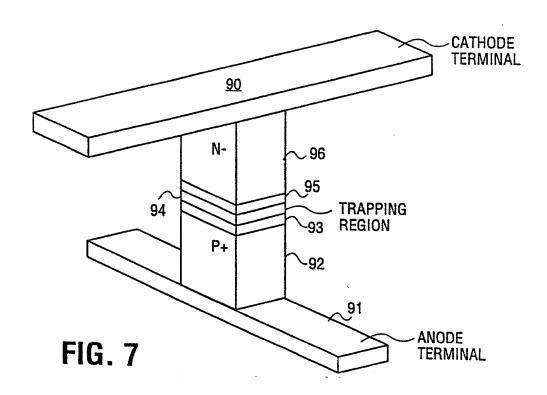
		P+		13.9 140]
	CONDUCTOR P+		UCTOR			_
			<u>142</u>			_
		ANTIFUSE		143		_)
144	N-	~133		N-		
	N+	132		N+		
	CONDUCTOR	131	141~	CONDUCTOR	- 121	
	N+	~ 130		N+		
	N- ·	~129		N-		
		ANTIF	USE	<u>128</u>		_
		P+	-	<u>127</u>		_ _
		CONDU	CTOR	<u>126</u>		_
		P-	+	<u>125</u>		

FIGURE 4B



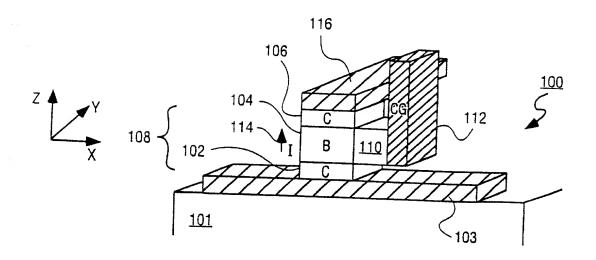
Title: NONVOLATILE MEMORY ON SOI AND COMPOUND SEMICONDUCTOR SUBSTRATES AND METHOD OF FABRICATION

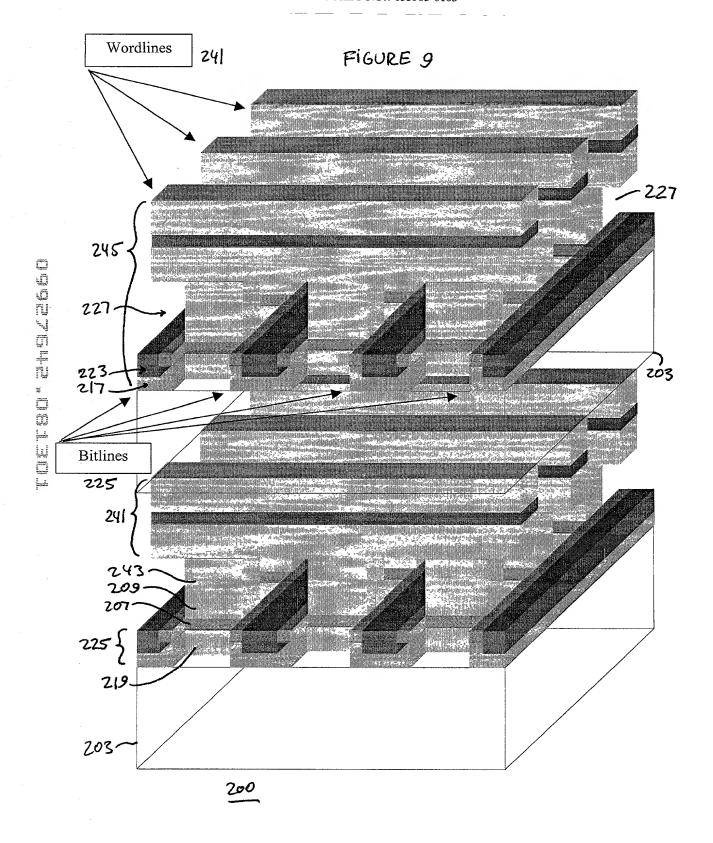




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FIGURE 8





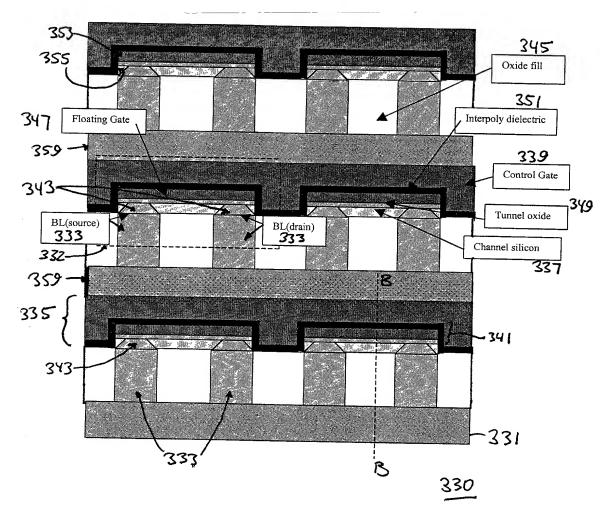


FIGURE 10A

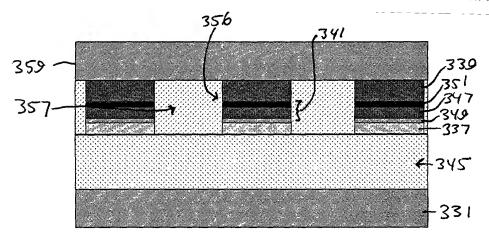
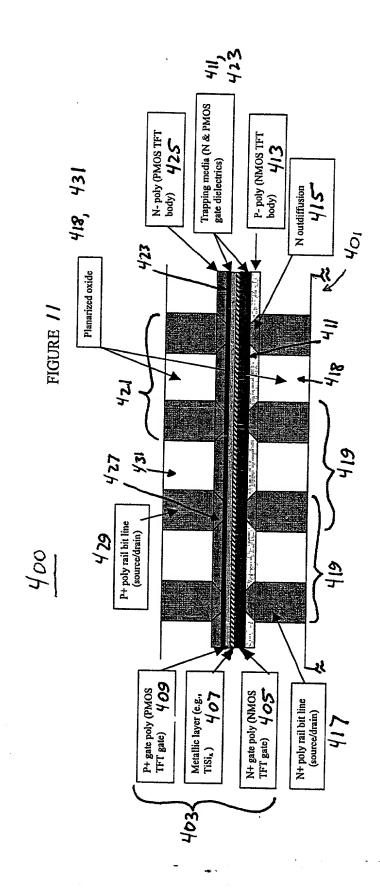
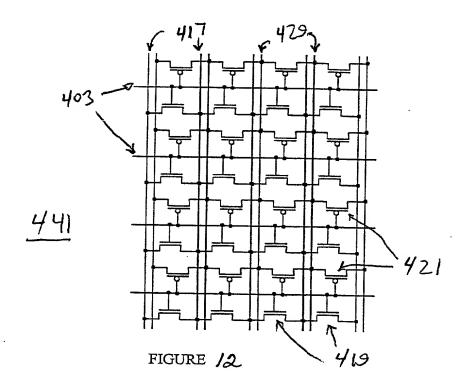
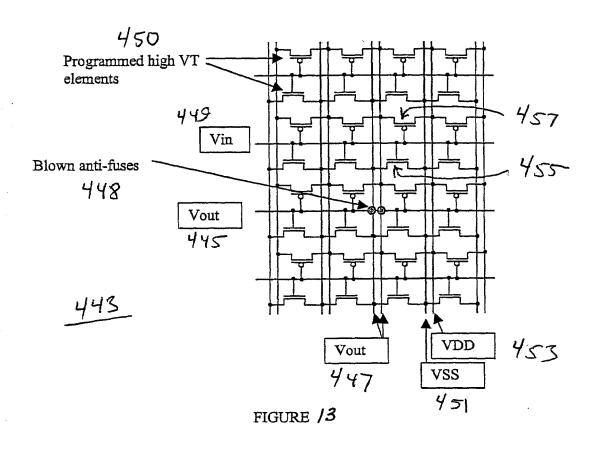


FIGURE 10B





Title: NONVOLATILE MEMORY ON SOI AND COMPOUND SEMICONDUCTOR SUBSTRATES AND METHOD OF FABRICATION Inventor(s): Andrew J. WALKER et al.



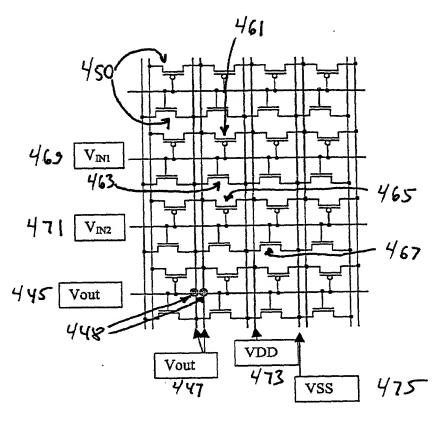


figure 14